# 74HC4851-Q100; 74HCT4851-Q100

## 8-channel analog multiplexer/demultiplexer with injection-current effect control

Rev. 3 — 18 February 2020

**Product** 

### 1. General description

The 74HC4851-Q100; 74HCT4851-Q100 are high-speed Si-gate CMOS devices and are specified in compliance with JEDEC standard no. 7A.

The 74HC4851-Q100; 74HCT4851-Q100 are 8-channel analog multiplexers/demultiplexers with three digital select inputs (S0 to S2), an active-LOW enable input (E), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). The devices feature injection-current effect control, which has excellent value in automotive applications where voltages in excess of the supply voltage are common.

With  $\overline{E}$  LOW, one of the eight switches is selected (low impedance ON-state) by S0 to S2. With  $\overline{E}$  HIGH, all switches are in the high-impedance OFF-state, independent of S0 to S2.

The injection-current effect control allows signals at disabled analog input channels to exceed the supply voltage without affecting the signal of the enabled analog channel. This eliminates the need for external diode/resistor networks typically used to keep the analog channel signals within the supply-voltage range.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Injection-current cross coupling < 1 mV/mA</li>
- Wide supply voltage range from 2.0 V to 6.0 V for 74HC4851-Q100
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Latch-up performance exceeds 100 mA per JESD 78 Class II level A
- Low ON-state resistance:
  - 400 Ω (typical) at V<sub>CC</sub> = 2.0 V
  - 215 Ω (typical) at V<sub>CC</sub> = 3.0 V
  - 120 Ω (typical) at V<sub>CC</sub> = 3.3 V
  - 76  $\Omega$  (typical) at  $V_{CC}$  = 4.5 V
  - 59 Ω (typical) at V<sub>CC</sub> = 6.0 V
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

## 3. Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating
- Automotive application

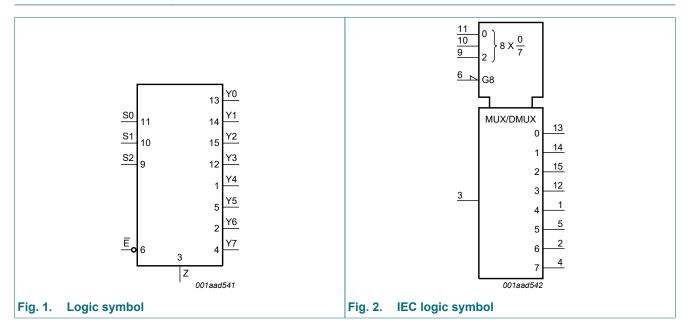


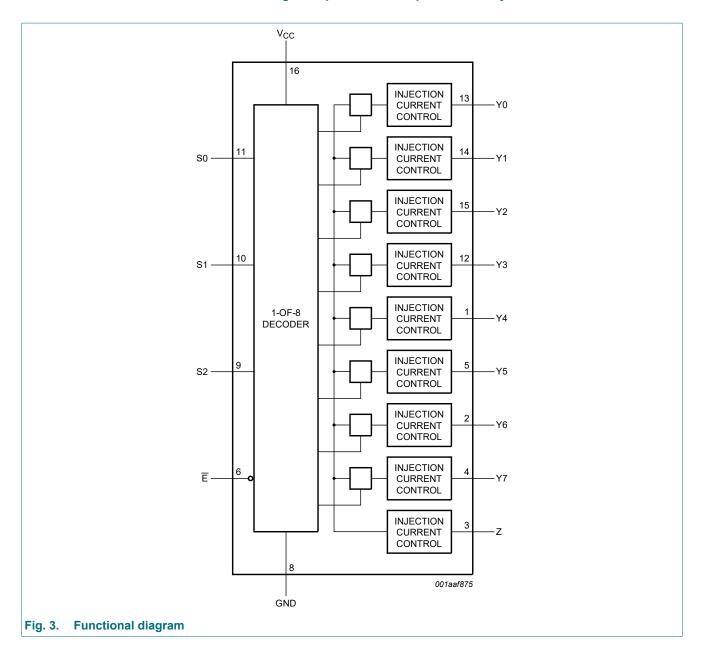
## 4. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74HC4851D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74HCT4851D-Q100			body width 3.9 mm	
74HC4851PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package;	SOT403-1
74HCT4851PW-Q100			16 leads; body width 4.4 mm	
74HC4851BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal	SOT763-1
74HCT4851BQ-Q100			enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm	

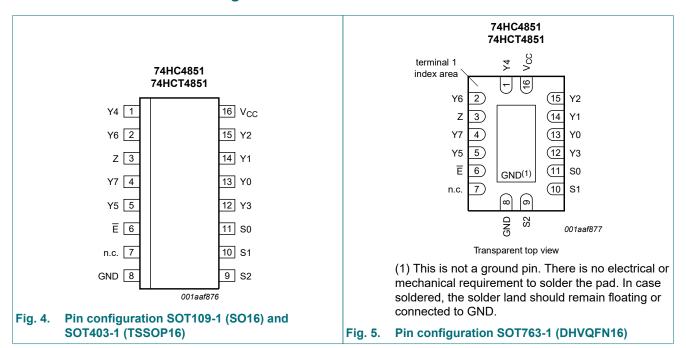
## 5. Functional diagram





## 6. Pinning information

#### 6.1. Pinning



#### 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Y4	1	independent input/output
Y6	2	independent input/output
Z	3	common input/output
Y7	4	independent input/output
Y5	5	independent input/output
Ē	6	enable input (active LOW)
n.c.	7	not connected
GND	8	ground (0 V)
S2	9	select input
S1	10	select input
S0	11	select input
Y3	12	independent input/output
Y0	13	independent input/output
Y1	14	independent input/output
Y2	15	independent input/output
V <sub>CC</sub>	16	supply voltage

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## 7. Functional description

#### Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$ 

Input				Channel ON
Ē	S2	S1	S0	
L	L	L	L	Y0 to Z
L	L	L	Н	Y1 to Z
L	L	Н	L	Y2 to Z
L	L	Н	Н	Y3 to Z
L	Н	L	L	Y4 to Z
L	Н	L	Н	Y5 to Z
L	Н	Н	L	Y6 to Z
L	Н	Н	Н	Y7 to Z
Н	X	Х	X	-

## 8. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
VI	input voltage	[1]	-0.5	V <sub>CC</sub> + 0.5	V
$V_{SW}$	switch voltage	[2]	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>SK</sub>	switch clamping current	$V_{SW}$ < -0.5 V or $V_{SW}$ > $V_{CC}$ + 0.5 V	-	±20	mA
I <sub>SW</sub>	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [3]	-	500	mW

- [1] The minimum and maximum input voltage rating may be exceeded if the input clamping current rating is observed.
- [2] The minimum and maximum switch voltage rating may be exceeded if the switch clamping current rating is observed.
- [3] For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P<sub>tot</sub> derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P<sub>tot</sub> derates linearly with 11.2 mW/K above 106 °C.

## 9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74H	74HC4851-Q100			74HCT4851-Q100		
			Min	Тур	Max	Min	Тур	Max	1
V <sub>CC</sub>	supply voltage		2.0	-	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
V <sub>SW</sub>	switch voltage		0	-	Vcc	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	6.0	1000	-	-	-	ns/V
		V <sub>CC</sub> = 3.0 V	-	6.0	800	-	-	-	ns/V
		V <sub>CC</sub> = 3.3 V	-	6.0	800	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	6.0	500	-	6.0	500	ns/V
		V <sub>CC</sub> = 6.0 V	-	6.0	400	-	-	-	ns/V

#### 10. Static characteristics

#### Table 6. R<sub>ON</sub> resistance

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Fig. 8.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC485	1-Q100									
R <sub>ON(peak)</sub>		$V_I = V_{CC}$ to GND; $\overline{E} = V_{IL}$								
	(peak)	$V_{CC}$ = 2.0 V; $I_{SW}$ = 2 mA	-	400	650	-	670	-	700	Ω
		$V_{CC} = 3.0 \text{ V}; I_{SW} \le 2 \text{ mA}$	-	215	330	-	360	-	380	Ω
		$V_{CC} = 3.3 \text{ V; } I_{SW} \le 2 \text{ mA}$	-	120	270	-	305	-	345	Ω
		V <sub>CC</sub> = 4.5 V; I <sub>SW</sub> ≤ 2 mA	-	76	210	-	240	-	270	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} \le 2 \text{ mA}$	-	59	195	-	220	-	250	Ω
ΔR <sub>ON</sub>	ON resistance	$V_I = 0.5 \times V_{CC}; \overline{E} = V_{IL}$								
	mismatch between	V <sub>CC</sub> = 2.0 V; I <sub>SW</sub> = 2 mA	-	4	10	-	15	-	20	Ω
	channels	$V_{CC} = 3.0 \text{ V}; I_{SW} \le 2 \text{ mA}$	-	2	8	-	12	-	16	Ω
		V <sub>CC</sub> = 3.3 V; I <sub>SW</sub> ≤ 2 mA	-	2	8	-	12	-	16	Ω
		V <sub>CC</sub> = 4.5 V; I <sub>SW</sub> ≤ 2 mA	-	2	8	-	12	-	16	Ω
İ		$V_{CC} = 6.0 \text{ V}; I_{SW} \le 2 \text{ mA}$	-	3	9	-	13	-	18	Ω
74HCT48	51-Q100									•
R <sub>ON(peak)</sub>	ON resistance	$V_I = V_{CC}$ to GND; $\overline{E} = V_{IL}$								
	(peak)	V <sub>CC</sub> = 4.5 V; I <sub>SW</sub> ≤ 2 mA	-	76	210	-	240	-	270	Ω
$\Delta R_{ON}$		$V_I = 0.5 \times V_{CC}; \overline{E} = V_{IL}$								
	mismatch between channels	V <sub>CC</sub> = 4.5 V; I <sub>SW</sub> ≤ 2 mA	-	2	8	-	12	-	16	Ω

#### Table 7. Injection current coupling

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Fig. 9.

Symbol	Parameter	Conditions	74H	1C4851-Q	100	74H	CT4851-C	100	Unit
			Min	Typ [1]	Max	Min	Typ [1]	Max	
T <sub>amb</sub> = -40 °C to +125 °C									
$\Delta V_{O}$	output voltage	$ I_{SW}  \le 1 \text{ mA}; R_S \le 3.9 \text{ k}\Omega$ [2][3]							
	variation	V <sub>CC</sub> = 3.3 V	-	0.05	1	-	-	-	mV
		V <sub>CC</sub> = 5.0 V	-	0.03	1	-	0.03	1	mV
		$ I_{SW}  \le 10 \text{ mA}; R_S \le 3.9 \text{ k}\Omega$							
		V <sub>CC</sub> = 3.3 V	-	0.55	5	-	-	-	mV
		V <sub>CC</sub> = 5.0 V	-	0.27	5	-	0.27	5	mV
		$ I_{SW}  \le 1 \text{ mA}; R_S \le 20 \text{ k}\Omega$							
		V <sub>CC</sub> = 3.3 V	-	0.04	2	-	-	-	mV
		V <sub>CC</sub> = 5.0 V	-	0.03	2	-	0.03	2	mV
		$ I_{SW}  \le 10 \text{ mA}; R_S \le 20 \text{ k}\Omega$							
		V <sub>CC</sub> = 3.3 V	-	0.56	20	-	-	-	mV
		V <sub>CC</sub> = 5.0 V	-	0.48	20	-	0.48	20	mV

Typical values are measured at  $T_{amb}$  = 25 °C.

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V);

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC48	51-Q100								'	
V <sub>IH</sub>	HIGH-level	control inputs								
	input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
		V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 3.3 V	2.3	-	-	2.3	-	2.3	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	control inputs								
	input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
		V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 3.3 V	-	-	1.0	-	1.0	-	1.0	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	-	1.8	-	1.8	V

 $<sup>\</sup>Delta V_O$  here is the maximum variation of output voltage of an enabled analog channel when current is injected into any disabled channel.

I<sub>SW</sub> = total current injected into all disabled channels.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	_	°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Ι <sub>Ι</sub>	input leakage current	control inputs; $V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 6.0 V	-	-	±0.1	-	±0.1	-	±1.0	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	$\overline{E}$ = V <sub>IH</sub> ; V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V; see <u>Fig. 6</u>								
		per channel	-	-	±0.1	-	±0.5	-	±1.0	μΑ
	all channels		-	-	±0.2	-	±2.0	-	±4.0	μΑ
I <sub>S(ON)</sub>	ON-state leakage current	$\overline{E}$ = V <sub>IL</sub> ; V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V; see <u>Fig. 7</u>	-	-	±0.1	-	±0.5	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	5.0	-	20.0	μΑ
C <sub>I</sub>	input capacitance	S0, S1, S2 and E	-	2	10	-	10	-	10	pF
C <sub>sw</sub>	switch	Z; OFF-state	-	15	40	-	40	-	40	pF
capacitance Yn; OF		Yn; OFF-state	-	3	15	-	15	-	15	pF
74HCT4	851-Q100									
V <sub>IH</sub>	HIGH-level control inputs; input voltage V <sub>CC</sub> = 4.5 V to 5.5 V		2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	control inputs; V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
l <sub>l</sub>	input leakage current	control inputs; $V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 5.5 V	-	-	±0.1	-	±0.1	-	±1.0	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	$\overline{E}$ = V <sub>IH</sub> ; V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V; see <u>Fig. 6</u>								
		per channel	-	-	±0.1	-	±0.5	-	±1.0	μΑ
		all channels	-	-	±0.2	-	±2.0	-	±4.0	μΑ
I <sub>S(ON)</sub>	ON-state leakage current	$E = V_{IL}$ ; $V_I = GND$ or $V_{CC}$ ; $V_O = V_{CC}$ or $GND$ ; $V_{CC} = 5.5$ V; see Fig. 7	-	-	±0.1	-	±0.5	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	2.0	-	5.0	-	20.0	μΑ
Δl <sub>CC</sub>	additional supply current	other inputs at V <sub>CC</sub> or GND;		-	300	-	370	-	370	μA
Cı	input capacitance	S0, S1, S2 and E	-	2	10	-	10	-	10	pF
C <sub>sw</sub>	switch	Z; OFF-state	-	15	40	-	40	-	40	pF
	capacitance	Yn; OFF-state	-	3	15	-	15	-	15	pF

current

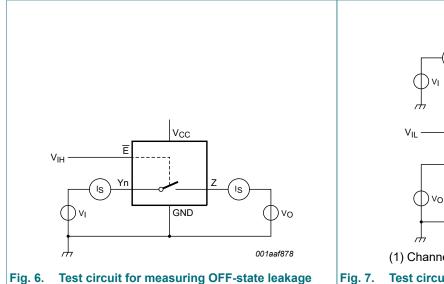
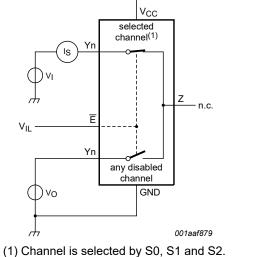
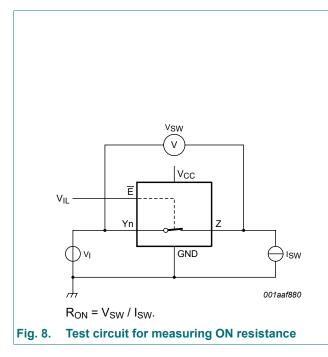


Fig. 6. Test circuit for measuring OFF-state leakage



Test circuit for measuring ON-state leakage



any disabled channel Yn Z Υn selected channel<sup>(1)</sup> Rs GND ν<sub>o</sub> 001aaf881 (1) Channel is selected by S0, S1 and S2.

 $V_{I}(1) < GND \text{ or } V_{I}(1) > V_{CC}.$  $GND < V_I(2) < V_{CC}$ 

Test circuit for injection current coupling Fig. 9.

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for test circuit see Fig. 14.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC48	51-Q100									
t <sub>pd</sub>	propagation	Z to Yn, Yn to Z; see Fig. 10 [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	10.0	25	-	29	-	32	ns
		V <sub>CC</sub> = 3.0 V	-	6.0	15.5	-	17.5	-	19.5	ns
		V <sub>CC</sub> = 3.3 V	-	5.0	14.5	-	16.5	-	18.5	ns
		V <sub>CC</sub> = 4.5 V	-	4.0	11.5	-	12.5	-	13.5	ns
		V <sub>CC</sub> = 6.0 V	-	3.0	10	-	11	-	12	ns
		Sn to Z, Sn to Yn; see Fig. 11 [1]								
		V <sub>CC</sub> = 2.0 V	-	18.0	32	-	35	-	40	ns
		V <sub>CC</sub> = 3.0 V	-	9.5	17.5	-	20	-	23	ns
		V <sub>CC</sub> = 3.3 V	-	8.5	16.5	-	19	-	22	ns
		V <sub>CC</sub> = 4.5 V	-	6.5	13	-	15	-	17	ns
		V <sub>CC</sub> = 6.0 V	-	5.0	12.5	-	14.5	-	16.5	ns
t <sub>en</sub>	enable time	Ē to Z, Ē to Yn; see Fig. 12 [2]								
		V <sub>CC</sub> = 2.0 V	-	-	95	-	105	-	115	ns
		V <sub>CC</sub> = 3.0 V	-	-	90	-	100	-	110	ns
		V <sub>CC</sub> = 3.3 V	-	-	85	-	95	-	105	ns
		V <sub>CC</sub> = 4.5 V	-	-	80	-	90	-	100	ns
		V <sub>CC</sub> = 6.0 V	-	-	78	-	80	-	80	ns
t <sub>dis</sub>	disable time	Ē to Z, Ē to Yn; see Fig. 12 [3]								
		V <sub>CC</sub> = 2.0 V	-	-	99	-	105	-	115	ns
		V <sub>CC</sub> = 3.0 V	-	-	90	-	100	-	110	ns
		V <sub>CC</sub> = 3.3 V	-	-	85	-	95	-	105	ns
		V <sub>CC</sub> = 4.5 V	-	-	80	-	90	-	100	ns
		V <sub>CC</sub> = 6.0 V	-	-	78	-	80	-	80	ns
C <sub>PD</sub>	power	per channel; see Fig. 13 [4]								
	dissipation capacitance	V <sub>CC</sub> = 3.3 V	-	28	-	-	-	-	-	pF
	capacitarice	V <sub>CC</sub> = 5.0 V	-	33	-	-	-	-	-	pF

Symbol	Parameter Conditions			25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
		Min	Тур	Max	Min	Max	Min	Max		
74HCT4	851-Q100									'
t <sub>pd</sub>	propagation	Z to Yn, Yn to Z; see Fig. 10 [1]								
	delay	V <sub>CC</sub> = 4.5 V	1.6	3.7	11.5	1.1	12.5	1.1	13.5	ns
		Sn to Z, Sn to Yn; see Fig. 11 [1]								
		V <sub>CC</sub> = 4.5 V	3.2	8.0	13	2.3	15	2.3	17	ns
t <sub>en</sub>	enable time	Ē to Z, Ē to Yn; see Fig. 12 [2]								
		V <sub>CC</sub> = 4.5 V	4.2	8.6	25	3.0	30	3.0	35	ns
t <sub>dis</sub>	disable time	Ē to Z, Ē to Yn; see Fig. 12 [3]								
		V <sub>CC</sub> = 4.5 V	28.5	64.7	80	28.2	90	28	100	ns
C <sub>PD</sub>	power	per channel; see Fig. 13 [4]								
dissipation capacitance		V <sub>CC</sub> = 5.0 V	-	30	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [2] t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.
- [3]  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$ 

C<sub>L</sub> = output load capacitance in pF;

C<sub>sw</sub> = switch capacitance in pF;

V<sub>CC</sub> = supply voltage in V.

#### 11.1. Waveforms and test circuit

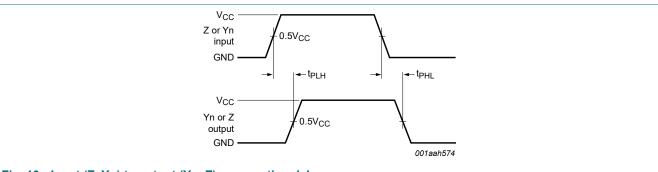
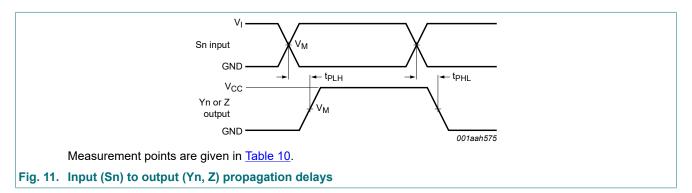
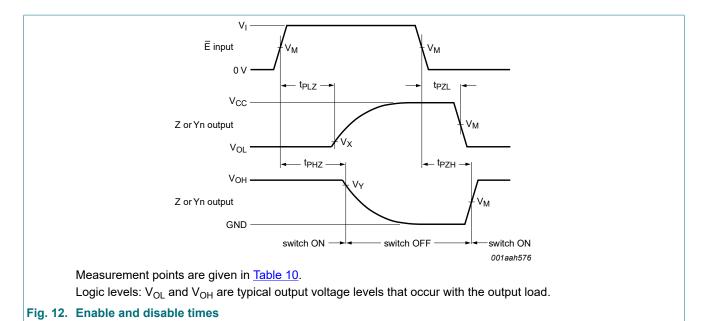


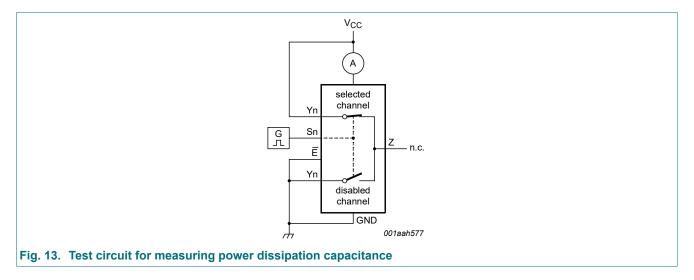
Fig. 10. Input (Z, Yn) to output (Yn, Z) propagation delays





**Table 10. Measurement points** 

Туре	Input		Output					
	V <sub>M</sub>	Vı	V <sub>M</sub> V <sub>X</sub> V <sub>Y</sub>					
74HC4851-Q100	0.5V <sub>CC</sub>	V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.1(V <sub>CC</sub> - V <sub>OL</sub> )	0.9V <sub>OH</sub>			
74HCT4851-Q100	1.3 V	3.0 V	0.5V <sub>CC</sub>	$V_{OL} + 0.1(V_{CC} - V_{OL})$	0.9V <sub>OH</sub>			



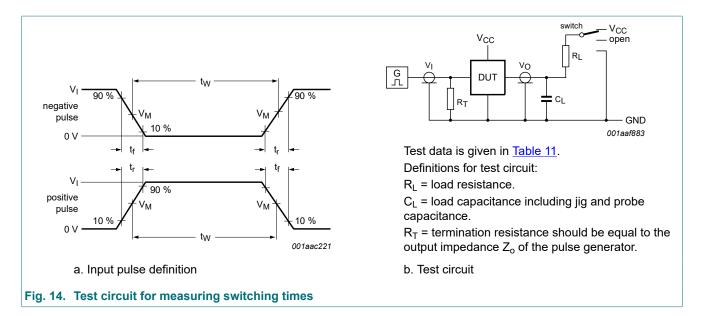


Table 11. Test data

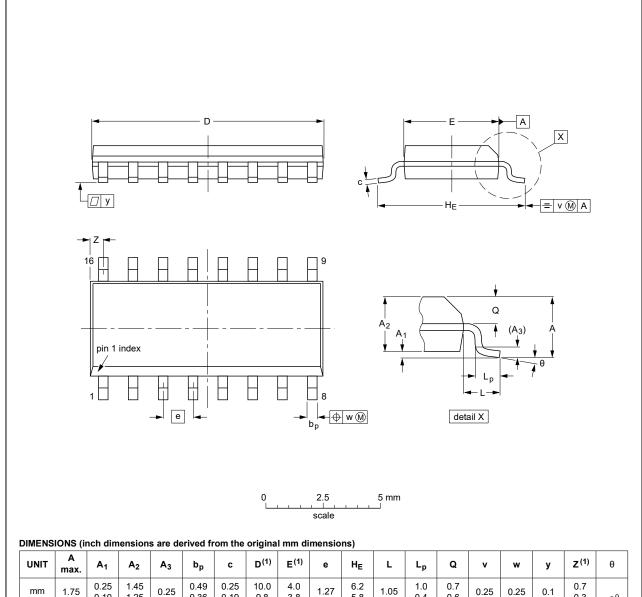
Test	Input			Output	S1 position	
	Control <b>Ē</b> , Sn	Switch Yn (Z)	t <sub>r</sub> , t <sub>f</sub>	Switch Z (Yn)		
	V <sub>I</sub> [1]	VI	_	C <sub>L</sub>	R <sub>L</sub>	
t <sub>PHL</sub> , t <sub>PLH</sub>	V <sub>CC</sub>	V <sub>CC</sub>	6 ns	50 pF	-	open
t <sub>PHZ</sub> , t <sub>PZH</sub>	V <sub>CC</sub>	V <sub>CC</sub>	6 ns	50 pF	10 kΩ	GND
t <sub>PLZ</sub> , t <sub>PZL</sub>	V <sub>CC</sub>	V <sub>CC</sub>	6 ns	50 pF	10 kΩ	V <sub>CC</sub>
C <sub>PD</sub>	V <sub>CC</sub>	V <sub>CC</sub>	6 ns	0 pF	-	open

[1] For 74HCT4851-Q100: input voltage  $V_1 = 3.0 \text{ V}$ .

## 12. Package outline

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	<b>A</b> <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

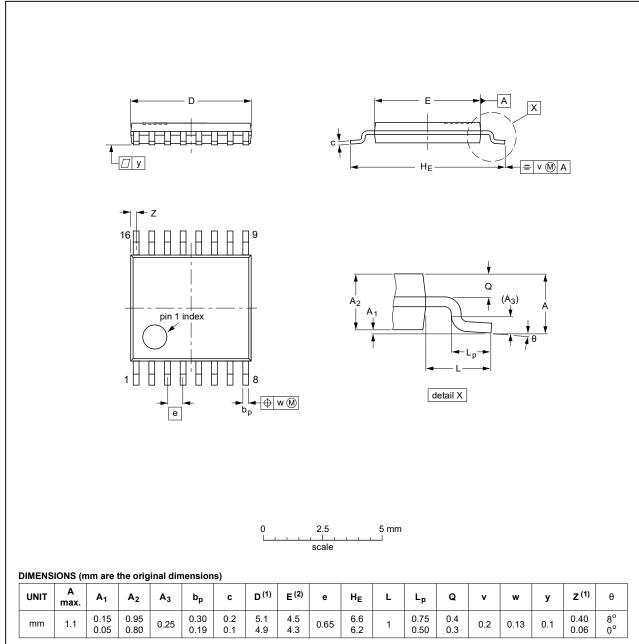
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

Fig. 15. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18	

Fig. 16. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

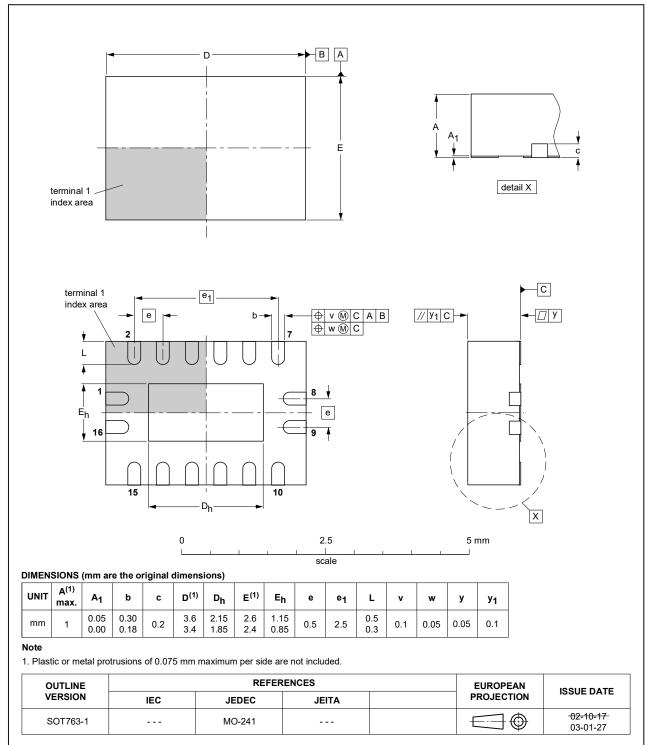


Fig. 17. Package outline SOT763-1 (DHVQFN16)

## 13. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model

## 14. Revision history

#### Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74HC_HCT4851_Q100 v.3	20200218	Product data sheet	-	74HC_HCT4851_Q100 v.2				
Modifications:	Section 2 updated.							
74HC_HCT4851_Q100 v.2	20180824	Product data sheet	-	74HC_HCT4851_Q100 v.1				
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>							
74HC_HCT4851_Q100 v.1	20120802	Product data sheet	-	-				

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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For more information, please visit: http://www.nexperia.com
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